

LMP7721

3 Femtoampere Input Bias Current Precision Amplifier

General Description

The LMP7721 is the industry's lowest guaranteed input bias current precision amplifier. The ultra low input bias current is 3 fA, with a guaranteed limit of ± 20 fA at 25°C and ± 900 fA at 85°C. This is achieved with the latest patent pending technology of input bias current cancellation amplifier circuitry. This technology also maintains the ultra low input bias current over the entire input common mode voltage range of the amplifier.

Other outstanding features, such as low voltage noise (6.5 nV/ $\sqrt{\text{Hz}}$), low DC offset voltage (± 150 μV maximum at 25°C) and low offset voltage temperature coefficient (-1.5 $\mu\text{V}/^\circ\text{C}$), improve system sensitivity and accuracy in high precision applications. With a supply voltage range of 1.8V to 5.5V, the LMP7721 is the ideal choice for battery operated portable applications. The LMP7721 is part of the LMP® precision amplifier family.

As part of National's PowerWise® products, the LMP7721 provides the remarkably wide gain bandwidth product (GBW) of 17 MHz while consuming only 1.3 mA of current. This wide GBW along with the high open loop gain of 120 dB enables accurate signal conditioning. With these specifications, the LMP7721 has the performance to excel in a wide variety of applications such as electrochemical cell amplifiers and sensor interface circuits.

The LMP7721 is offered in an 8-pin SOIC package with a special pinout that isolates the amplifier's input from the power supply and output pins. With proper board layout techniques, the unique pinout of the LMP7721 will prevent PCB leakage current from reaching the input pins. Thus system error will be further reduced.

Features

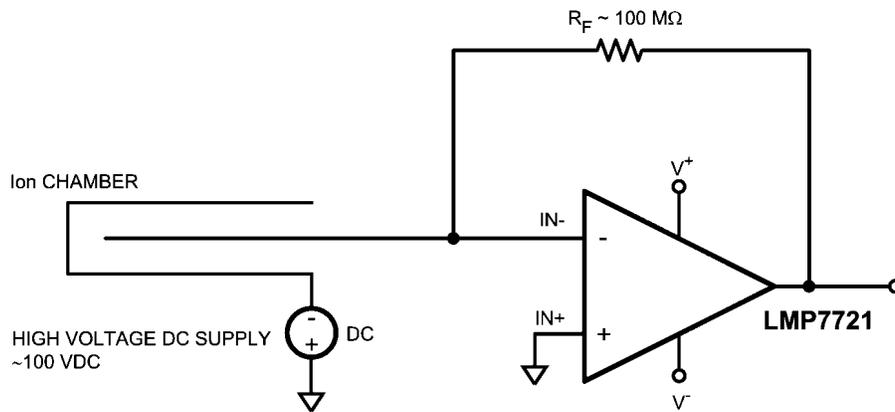
Unless otherwise noted, typical values at $T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$.

- Input bias current ($V_{CM} = 1\text{V}$)
 - max @ 25°C ±20 fA
 - max @ 85°C ±900 fA
- Offset voltage ±26 μV
- Offset voltage drift -1.5 $\mu\text{V}/^\circ\text{C}$
- DC Open loop gain 120 dB
- DC CMRR 100 dB
- Input voltage noise (at $f = 1$ kHz) 6.5 nV/ $\sqrt{\text{Hz}}$
- THD 0.0007%
- Supply current 1.3 mA
- GBW 17 MHz
- Slew rate (falling edge) 12.76 V/ μs
- Supply voltage 1.8V to 5.5V
- Operating temperature range -40°C to 125°C
- 8-Pin SOIC

Applications

- Photodiode amplifier
- High impedance sensor amplifier
- Ion chamber amplifier
- Electrometer amplifier
- pH electrode amplifier
- Transimpedance amplifier

Block Diagram of a Typical Application



Ion Chamber: Current to Voltage Converter

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PowerWise® is a registered trademark of National Semiconductor.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance (Note 2)	
Human Body Model	2000V
Machine Model	200V
V_{IN} Differential	$\pm 0.3V$
Supply Voltage ($V_S = V^+ - V^-$) (Note 10)	6.0V
Voltage on Input/Output Pins	$V^+ + 0.3V, V^- - 0.3V$
Storage Temperature Range	$-65^\circ C$ to $150^\circ C$
Junction Temperature (Note 3)	$+150^\circ C$

Soldering Information

Infrared or Convection (20 sec)	$235^\circ C$
Wave Soldering Lead Temp. (10 sec)	$260^\circ C$

Operating Ratings (Note 1)

Temperature Range (Note 3)	$-40^\circ C$ to $125^\circ C$
Supply Voltage ($V_S = V^+ - V^-$)	$1.8V$ to $5.5V$
$0^\circ C \leq T_A \leq 125^\circ C$	$1.8V$ to $5.5V$
$-40^\circ C \leq T_A \leq 125^\circ C$	$2.0V$ to $5.5V$
Package Thermal Resistance (θ_{JA}) (Note 3)	$190^\circ C/W$
8-Pin SOIC	

2.5V Electrical Characteristics

Unless otherwise specified, all limits are guaranteed for $T_A = 25^\circ C$, $V^+ = 2.5V$, $V^- = 0V$, $V_{CM} = (V^+ + V^-)/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 5)	Typ (Note 4)	Max (Note 5)	Units
V_{OS}	Input Offset Voltage			± 50	± 180 ± 480	μV
TC V_{OS}	Input Offset Voltage Drift (Note 6)			-1.5	-4	$\mu V/^\circ C$
I_{BIAS}	Input Bias Current	$V_{CM} = 1V$ (Notes 7, 8)	$25^\circ C$	± 3	± 20	fA
			$-40^\circ C$ to $85^\circ C$		± 900	
			$-40^\circ C$ to $125^\circ C$		± 5	pA
I_{OS}	Input Offset Current	$V_{CM} = 1V$ (Note 8)		6	40	fA
CMRR	Common Mode Rejection Ratio	$0V \leq V_{CM} \leq 1.4V$	83 80	100		dB
PSRR	Power Supply Rejection Ratio	$1.8V \leq V^+ \leq 5.5V$ $V^- = 0V, V_{CM} = 0$	84 80	92		dB
CMVR	Input Common-Mode Voltage Range	CMRR ≥ 80 dB CMRR ≥ 78 dB	-0.3 -0.3		1.5 1.5	V
A_{VOL}	Large Signal Voltage Gain	$V_O = 0.15V$ to $2.2V$ $R_L = 2 k\Omega$ to $V^+/2$	88 82	107		dB
		$V_O = 0.15V$ to $2.2V$ $R_L = 10 k\Omega$ to $V^+/2$	92 88	120		
V_O	Output Swing High	$R_L = 2 k\Omega$ to $V^+/2$	70 77	25		mV from V^+
		$R_L = 10 k\Omega$ to $V^+/2$	60 66	20		
	Output Swing Low	$R_L = 2 k\Omega$ to $V^+/2$		30	70 73	mV
		$R_L = 10 k\Omega$ to $V^+/2$		15	60 62	
I_O	Output Short Circuit Current	Sourcing to V^- $V_{IN} = 200$ mV (Note 9)	36 30	46		mA
		Sinking to V^+ $V_{IN} = -200$ mV (Note 9)	7.5 5.0	15		
I_S	Supply Current			1.1	1.5 1.75	mA
SR	Slew Rate	$A_V = +1$, Rising (10% to 90%)		9.3		V/ μs
		$A_V = +1$, Falling (90% to 10%)		10.8		

Symbol	Parameter	Conditions	Min (Note 5)	Typ (Note 4)	Max (Note 5)	Units
GBW	Gain Bandwidth Product			15		MHz
e_n	Input-Referred Voltage Noise	$f = 400 \text{ Hz}$		8		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1 \text{ kHz}$		7		
i_n	Input-Referred Current Noise	$f = 1 \text{ kHz}$		0.01		$\text{pA}/\sqrt{\text{Hz}}$
THD+N	Total Harmonic Distortion + Noise	$f = 1 \text{ kHz}, A_V = 2, R_L = 100 \text{ k}\Omega$ $V_O = 0.9 V_{PP}$		0.003		%
		$f = 1 \text{ kHz}, A_V = 2, R_L = 600\Omega$ $V_O = 0.9 V_{PP}$		0.003		

5V Electrical Characteristics

Unless otherwise specified, all limits are guaranteed for $T_A = 25^\circ\text{C}$, $V^+ = 5\text{V}$, $V^- = 0\text{V}$, $V_{CM} = (V^+ + V^-)/2$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (Note 5)	Typ (Note 4)	Max (Note 5)	Units
V_{OS}	Input Offset Voltage			± 26	± 150 ± 450	μV
TC V_{OS}	Input Offset Average Drift (Note 6)			-1.5	-4	$\mu\text{V}/^\circ\text{C}$
I_{BIAS}	Input Bias Current	$V_{CM} = 1\text{V}$ (Notes 7, 8)	25°C	± 3	± 20	fA
			-40°C to 85°C		± 900	
			-40°C to 125°C		± 5	pA
I_{OS}	Input Offset Current	(Note 8)		6	40	fA
CMRR	Common Mode Rejection Ratio	$0\text{V} \leq V_{CM} \leq 3.7\text{V}$	84 82	100		dB
PSRR	Power Supply Rejection Ratio	$1.8\text{V} \leq V^+ \leq 5.5\text{V}$ $V^- = 0\text{V}, V_{CM} = 0$	84 80	96		dB
CMVR	Input Common-Mode Voltage Range	CMRR $\geq 80 \text{ dB}$ CMRR $\geq 78 \text{ dB}$	-0.3 -0.3		4 4	V
A_{VOL}	Large Signal Voltage Gain	$V_O = 0.3\text{V}$ to 4.7V $R_L = 2 \text{ k}\Omega$ to $V^+/2$	88 82	111		dB
		$V_O = 0.3\text{V}$ to 4.7V $R_L = 10 \text{ k}\Omega$ to $V^+/2$	92 88	120		
V_O	Output Swing High	$R_L = 2 \text{ k}\Omega$ to $V^+/2$	70 77	30		mV from V^+
		$R_L = 10 \text{ k}\Omega$ to $V^+/2$	60 66	20		
	Output Swing Low	$R_L = 2 \text{ k}\Omega$ to $V^+/2$		31	70 73	mV
		$R_L = 10 \text{ k}\Omega$ to $V^+/2$		20	60 62	
I_O	Output Short Circuit Current	Sourcing to V^- $V_{IN} = 200 \text{ mV}$ (Note 9)	46 38	60		mA
		Sinking to V^+ $V_{IN} = -200 \text{ mV}$ (Note 9)	10.5 6.5	22		
I_S	Supply Current			1.3	1.7 1.95	mA
SR	Slew Rate	$A_V = +1$, Rising (10% to 90%)		10.43		V/ μs
		$A_V = +1$, Falling (90% to 10%)		12.76		
GBW	Gain Bandwidth Product			17		MHz

Symbol	Parameter	Conditions	Min (Note 5)	Typ (Note 4)	Max (Note 5)	Units
e_n	Input-Referred Voltage Noise	$f = 400 \text{ Hz}$		7.5		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1 \text{ kHz}$		6.5		
i_n	Input-Referred Current Noise	$f = 1 \text{ kHz}$		0.01		$\text{pA}/\sqrt{\text{Hz}}$
THD+N	Total Harmonic Distortion + Noise	$f = 1 \text{ kHz}, A_V = 2, R_L = 100 \text{ k}\Omega$ $V_O = 4 V_{PP}$		0.0007		%
		$f = 1 \text{ kHz}, A_V = 2, R_L = 600\Omega$ $V_O = 4 V_{PP}$		0.0007		

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics Tables.

Note 2: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

Note 3: The maximum power dissipation is a function of $T_{J(\text{MAX})}$, θ_{JA} . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(\text{MAX})} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly onto a PC Board.

Note 4: Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

Note 5: Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using the Statistical Quality Control (SQC) method.

Note 6: Offset voltage average drift is determined by dividing the change in V_{OS} at the temperature extremes by the total temperature change.

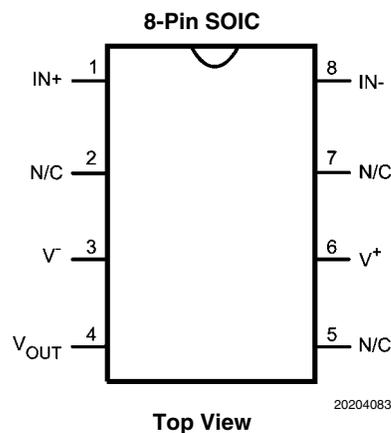
Note 7: Positive current corresponds to current flowing into the device.

Note 8: This parameter is guaranteed by design and/or characterization and is not tested in production.

Note 9: The short circuit test is a momentary open loop test.

Note 10: The voltage on any pin should not exceed 6V relative to any other pins.

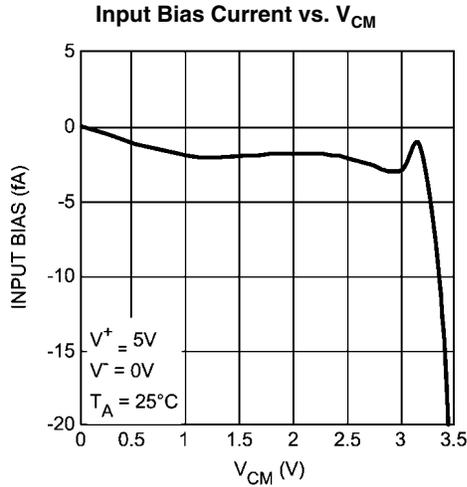
Connection Diagram



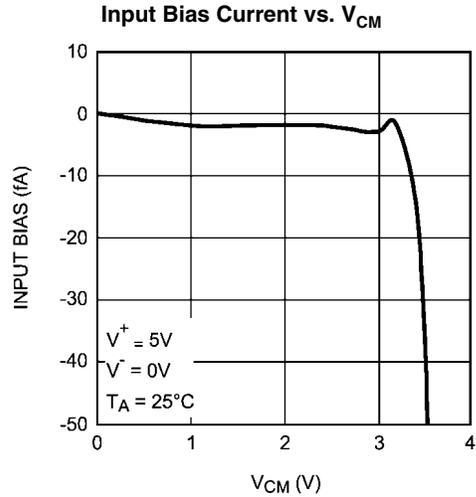
Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing
8-Pin SOIC	LMP7721MA	LMP7721MA	95 Units/Rail	M08A
	LMP7721MAX		2.5k Units Tape and Reel	

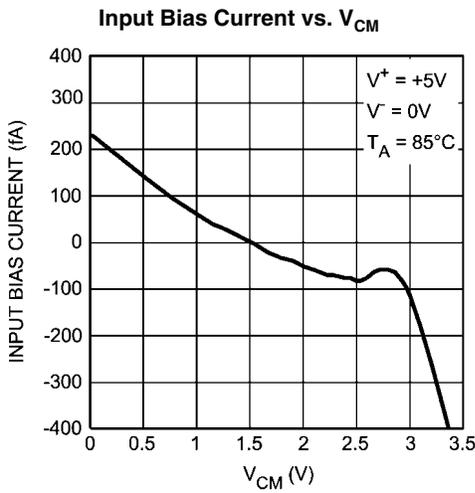
Typical Performance Characteristics Unless otherwise specified: $T_A = 25^\circ\text{C}$, $V_{CM} = (V^+ + V^-)/2$.



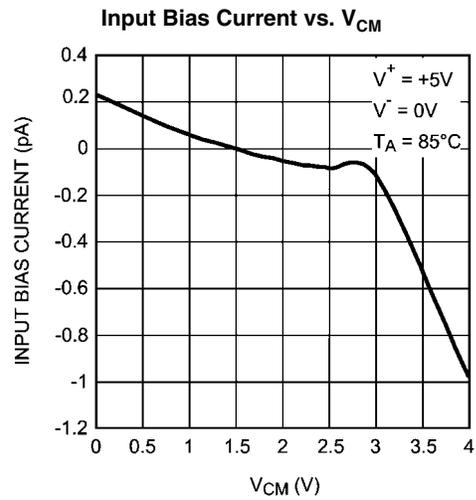
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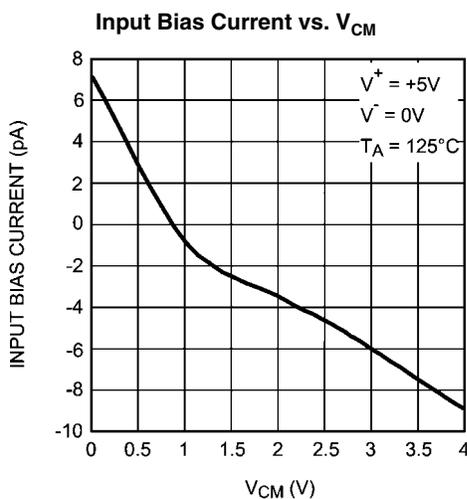
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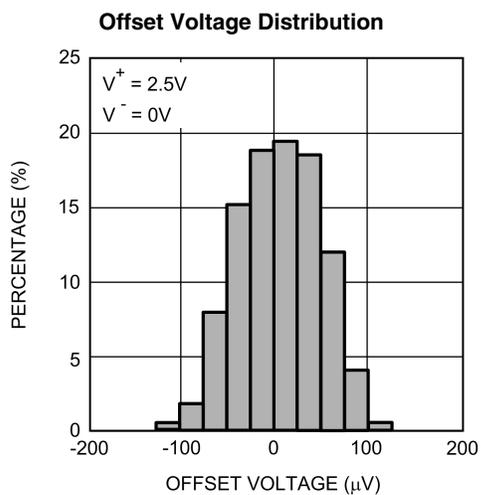
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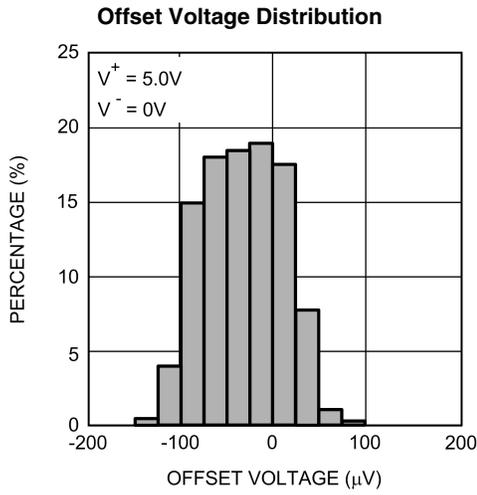
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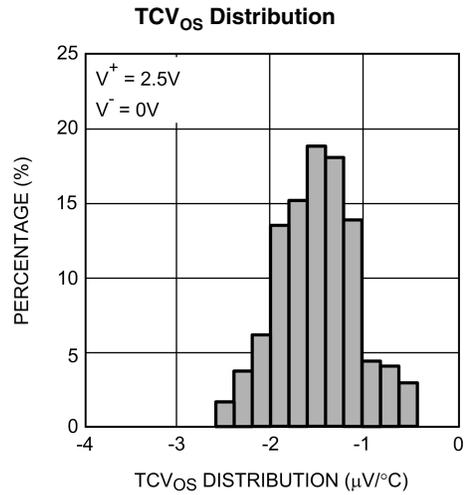
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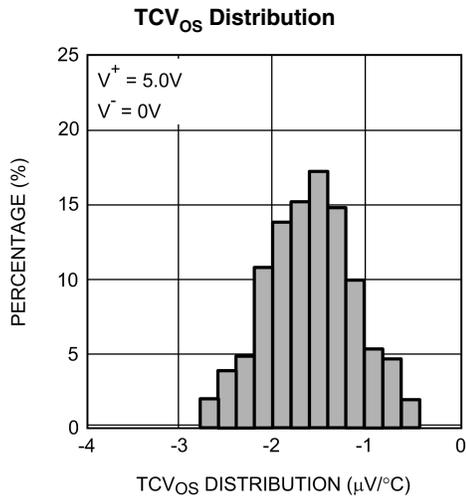
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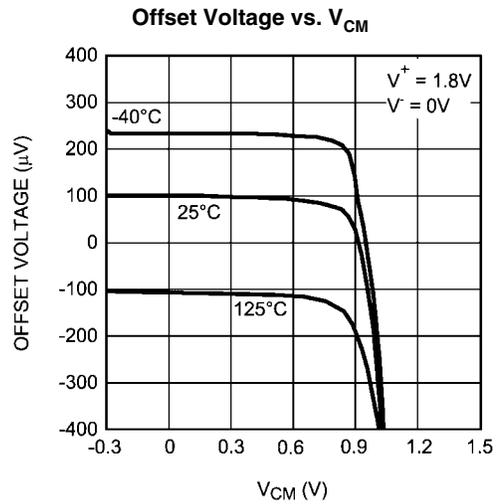
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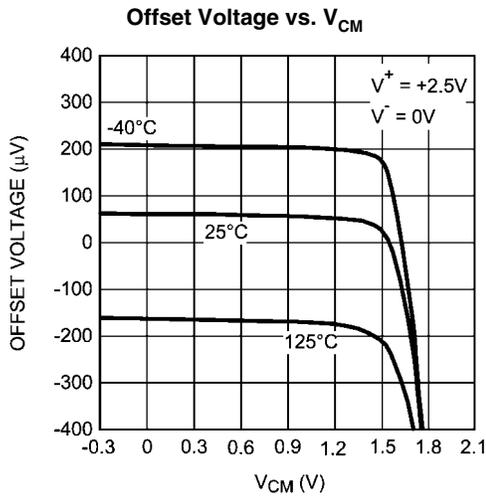
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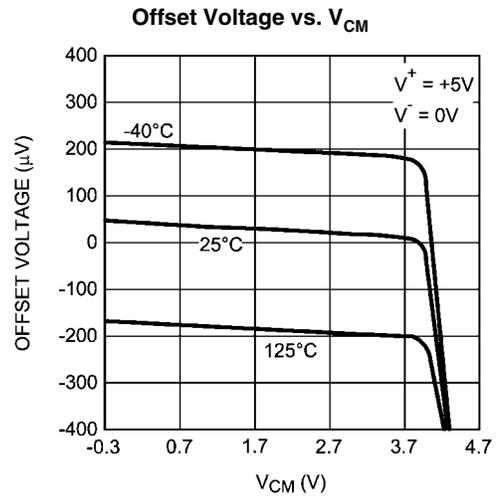
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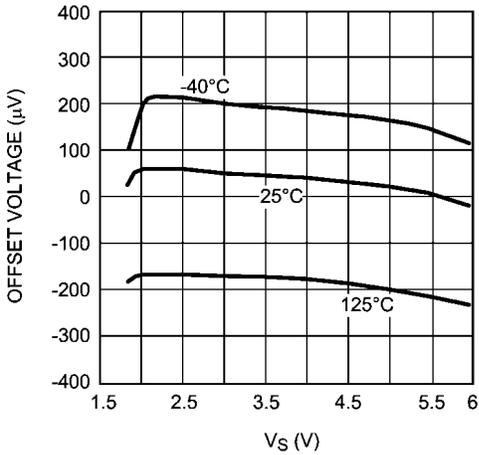


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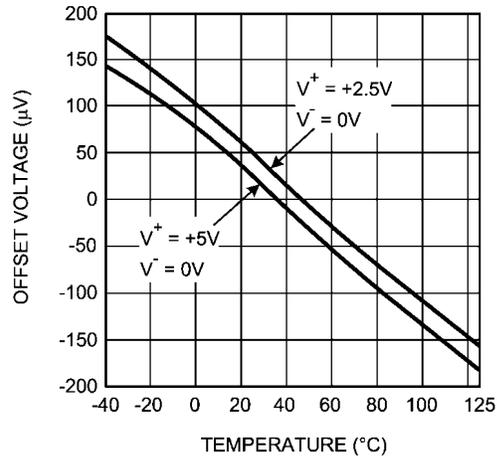
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Offset Voltage vs. Supply Voltage



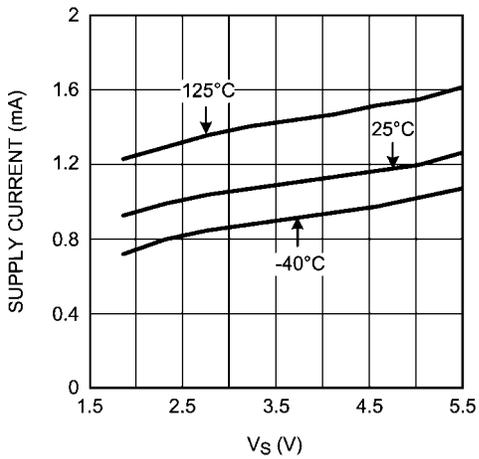
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Offset Voltage vs. Temperature



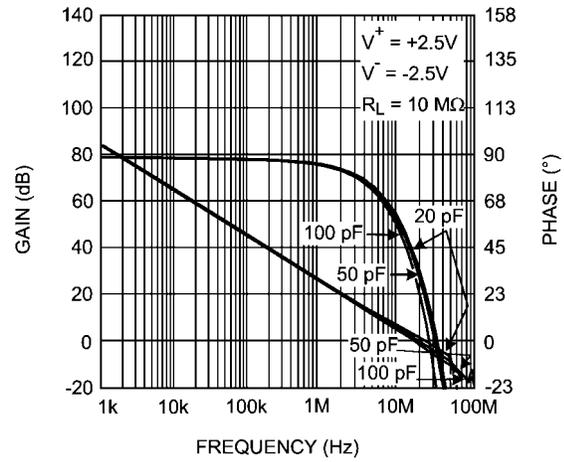
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Supply Current vs. Supply Voltage



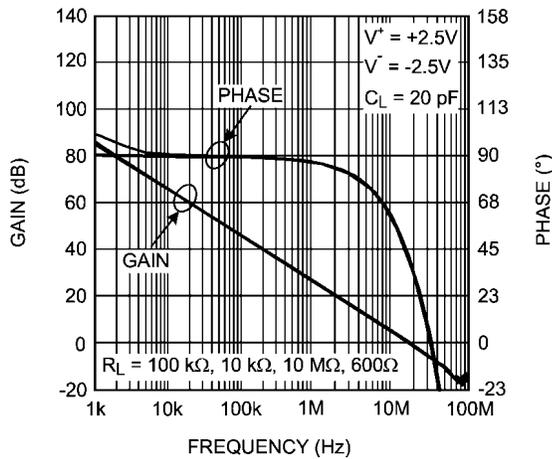
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Open Loop Frequency Response Gain and Phase



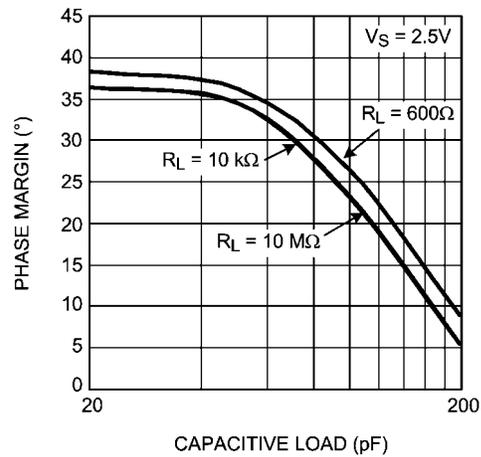
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Open Loop Frequency Response Gain and Phase



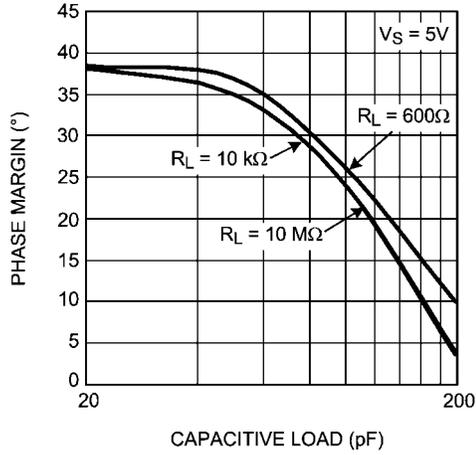
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Phase Margin vs. Capacitive Load



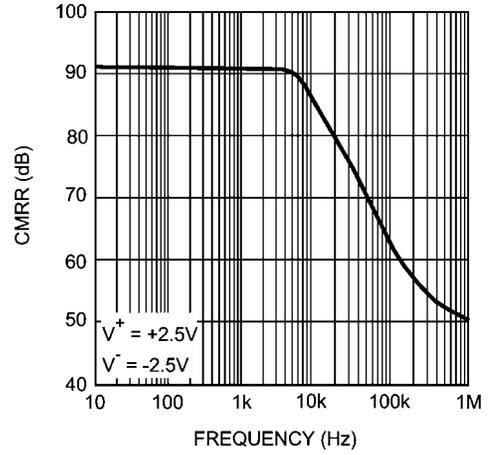
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Phase Margin vs. Capacitive Load



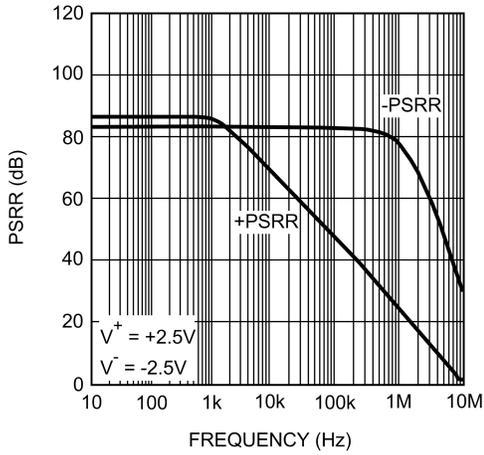
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CMRR vs. Frequency



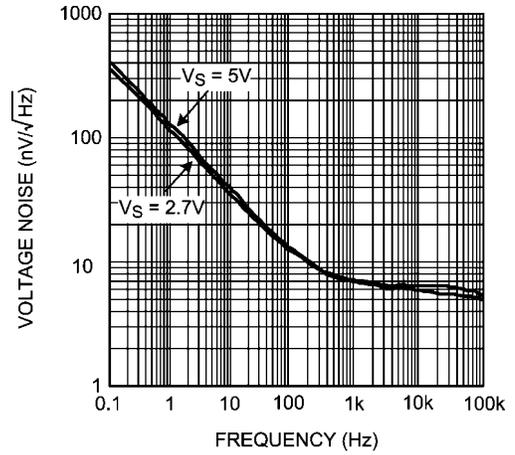
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PSRR vs. Frequency



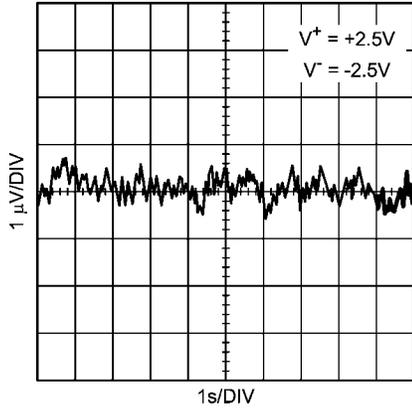
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Input Referred Voltage Noise vs. Frequency



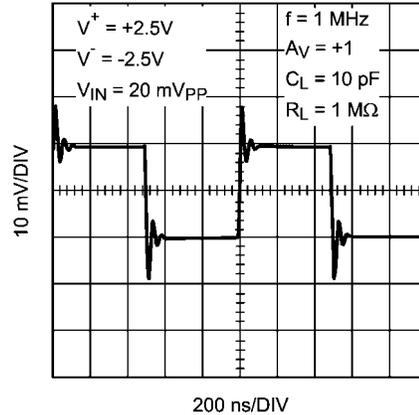
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Time Domain Voltage Noise



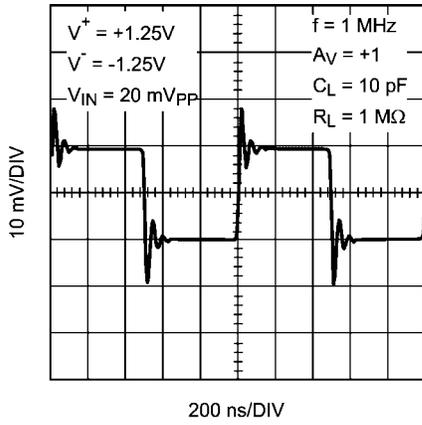
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Small Signal Step Response



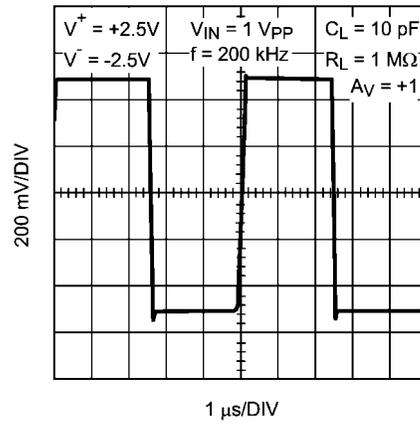
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Small Signal Step Response



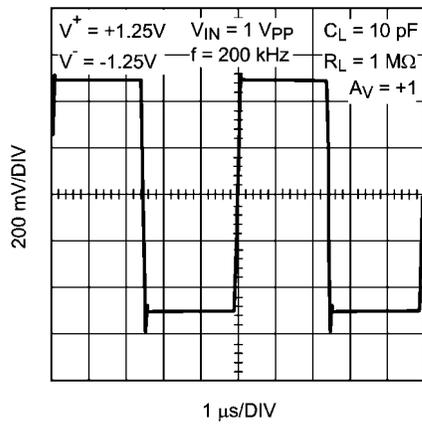
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Large Signal Step Response



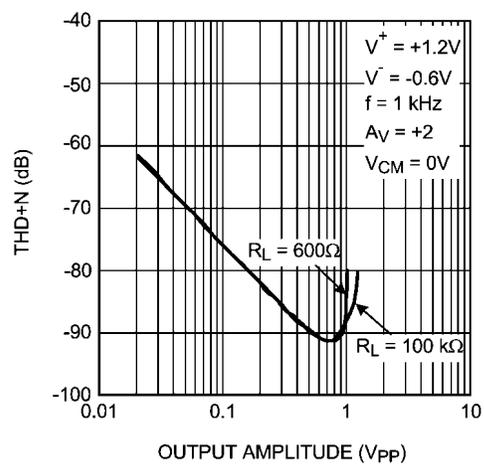
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Large Signal Step Response



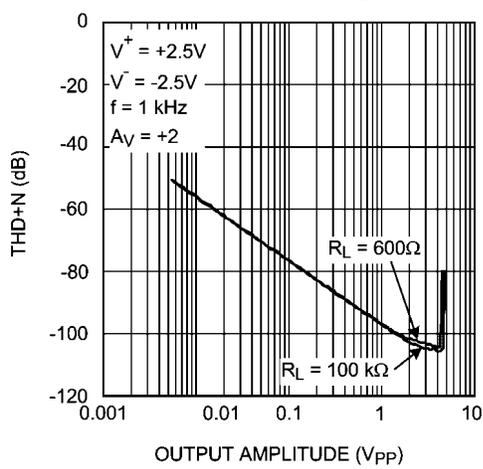
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THD+N vs. Output Voltage



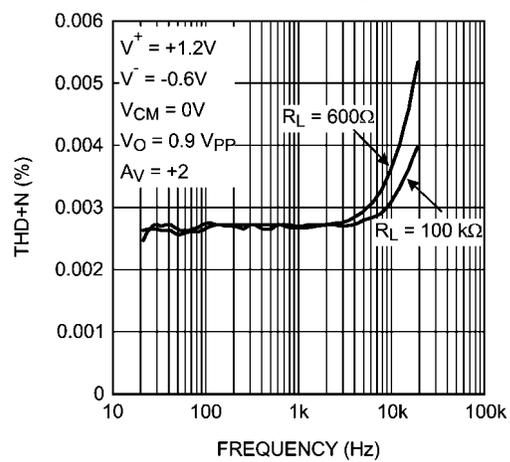
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THD+N vs. Output Voltage



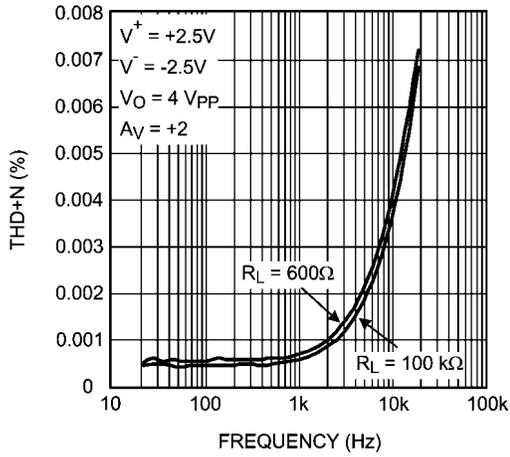
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THD+N vs. Frequency



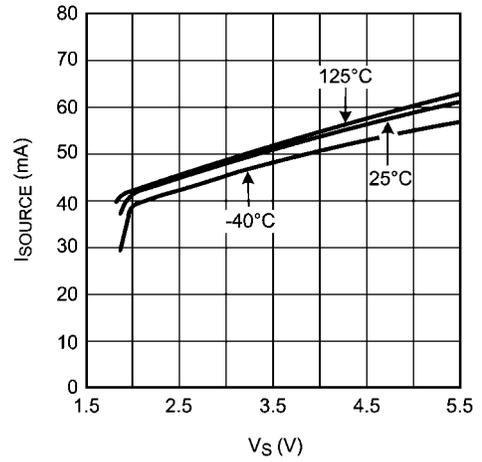
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THD+N vs. Frequency



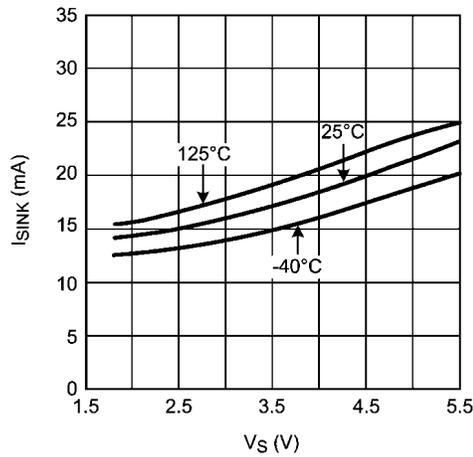
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Sourcing Current vs. Supply Voltage



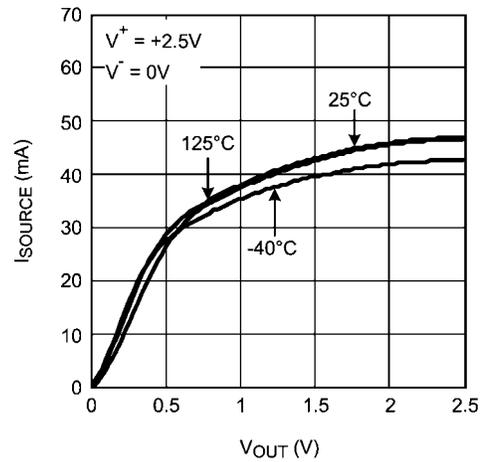
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Sinking Current vs. Supply Voltage



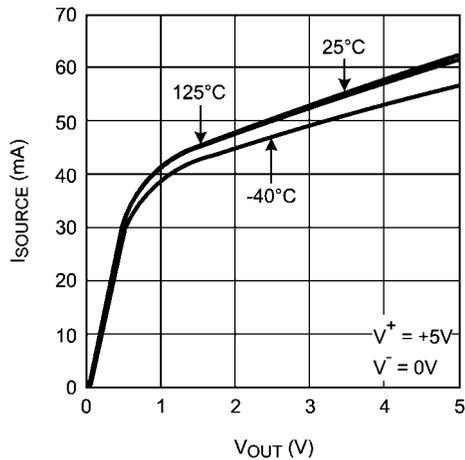
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Sourcing Current vs. Output Voltage



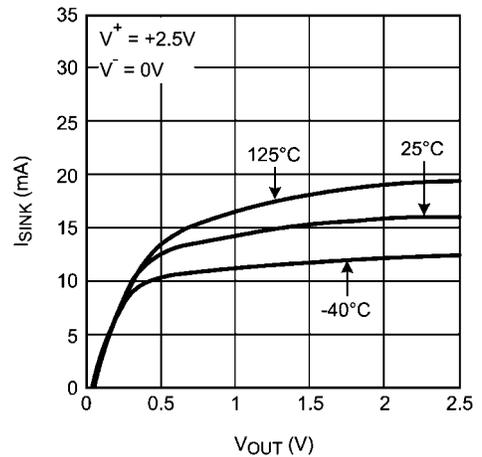
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Sourcing Current vs. Output Voltage



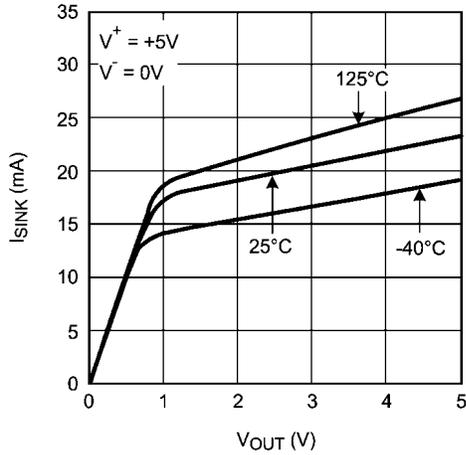
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Sinking Current vs. Output Voltage



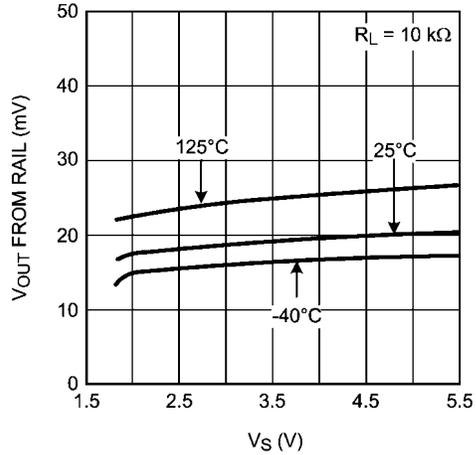
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Sinking Current vs. Output Voltage



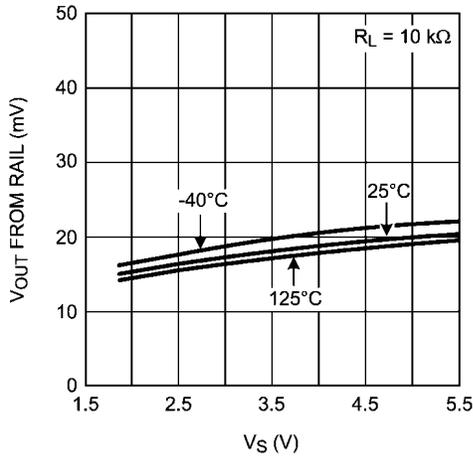
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Output Swing High vs. Supply Voltage



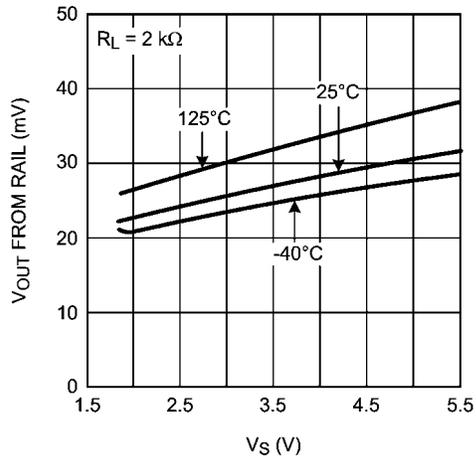
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Output Swing Low vs. Supply Voltage



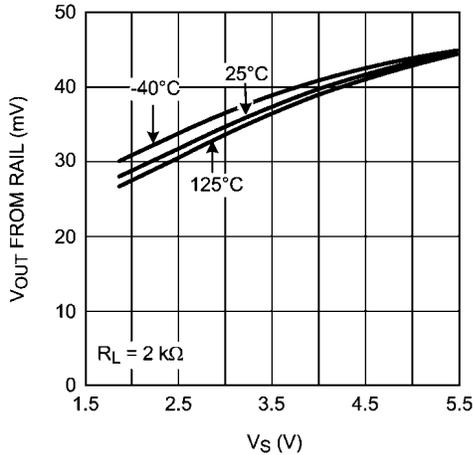
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Output Swing High vs. Supply Voltage



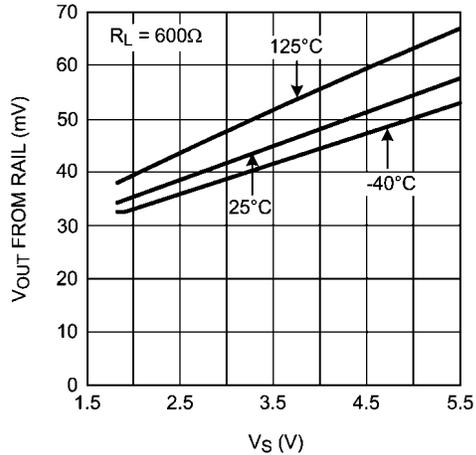
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Output Swing Low vs. Supply Voltage

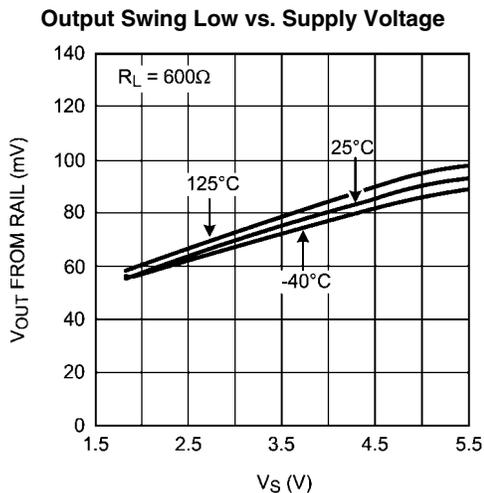


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Output Swing High vs. Supply Voltage



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Application Information

ADVANTAGES OF THE LMP7721

Ultra Low Input Bias Current

The LMP7721 has the industry's lowest guaranteed input bias current. The ultra low input bias current is typically 3 fA, with a guaranteed limit of ± 20 fA at 25°C, ± 900 fA at 85°C and ± 5 pA at 125°C when $V_{CM} = 1$ V with a 5V or a 2.5V power supply.

Wide Bandwidth at Low Supply Current

The LMP7721 is a high performance amplifier that provides a 17 MHz unity gain bandwidth while drawing only 1.3 mA of current. This makes the LMP7721 ideal for wideband amplification in portable applications.

Low Input Referred Noise

The LMP7721 has a low input referred voltage noise density (6.5 nV/√Hz at 1 kHz with 5V supply). Its MOS input stage ensures a very low input referred current noise density (0.01 pA/√Hz).

The low input referred noise and the ultra low input bias current make the LMP7721 stand out in maintaining signal fidelity. This quality makes the LMP7721 a suitable candidate for sensor based applications.

Low Supply Voltage

The LMP7721 has performance guaranteed at 2.5V and 5V power supplies. The LMP7721 is guaranteed to be functional at all supply voltages between 2.0V to 5.5V, for ambient temperatures ranging from -40°C to 125°C. This means that the LMP7721 has a long operational span over the battery's lifetime. The LMP7721 is also guaranteed to be functional at 1.8V supply voltage, for ambient temperatures ranging from 0°C to 125°C. This makes the LMP7721 ideal for use in low voltage commercial applications.

RRO and Ground Sensing

Rail-to-rail output swing provides the maximum possible output dynamic range. This is particularly important when operating at low supply voltages. An innovative positive feedback scheme is created to boost the LMP7721's output current drive capability. This allows the LMP7721 to source 30 mA to 40 mA of current at 1.8V power supply.

The LMP7721's input common mode range includes the negative supply rail which makes direct sensing at ground possible in single supply operation.

Unique Pinout

The LMP7721 has been designed with the IN+ and IN-, V+ and V- pins on opposite sides of the package. There are isolation pins between IN+ and V-, IN- and V+. This unique pinout makes it easy to guard the LMP7721's input. This pinout design reduces the input bias current's dependence on common mode or supply bias.

The SOIC package features low leakage and it has large pin spacing. This lowers the probability of dust particles settling down between two pins thus reducing the resistance between the pins which can be a problem.

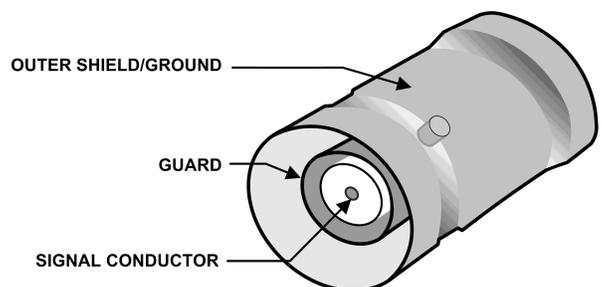
Input Protection

The LMP7721 input stage is protected from seeing excessive differential input voltage by a pair of back-to-back diodes attached between the inputs. This limits the differential voltage and hence prevents phase inversion as well as any performance drift. These diodes can conduct current when the input signal has a really fast edge, and, if necessary, should be isolated (using a resistor or a current follower) in such cases.

SYSTEM DESIGN TECHNIQUES WITH THE LMP7721

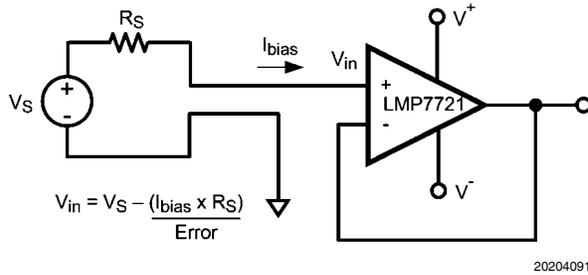
In order to take full advantage of the LMP7721's ultra low input bias current, a triaxial cable/connector is recommended when designing application systems.

A triaxial cable/connector is similar to a coaxial cable/connector and is often referred to as "triax". Figure 1 shows the structure of the triax.



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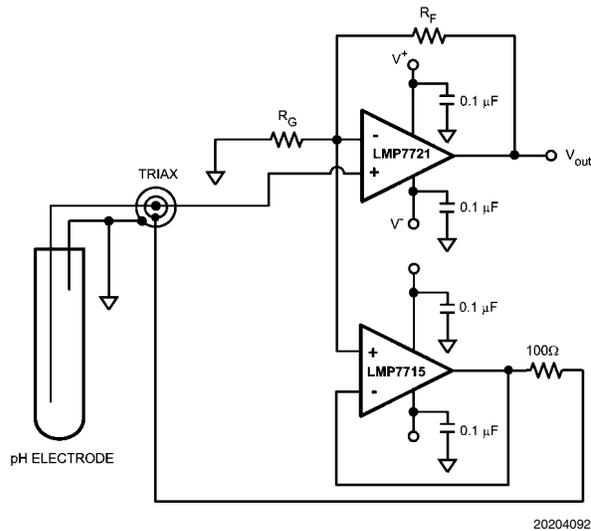
FIGURE 1. The Structure of a Triax



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FIGURE 4. Error Caused by Amplifier's Input Bias Current and Sensor Source Impedance

Figure 5 is an example of the LMP7721 used as a pH sensor amplifier.



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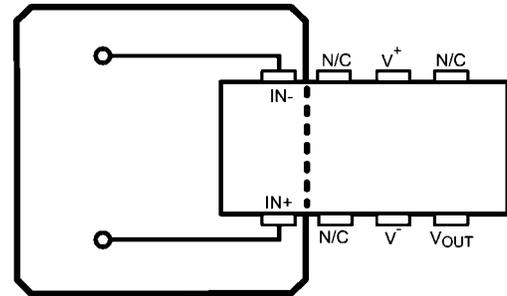
FIGURE 5. LMP7721 as pH Electrode Amplifier

The output voltage from the pH electrode is fed to the signal conductor of the triax and then sent to the non-inverting input of the LMP7721. In this application, the inverting input is a low impedance node and hence is used to drive the LMP7715

which acts as a guard driver. The output of the guard driver is connected to the guard of the triax via a 100Ω isolation resistor. Ideally, the inverting and the non-inverting inputs of the amplifier are kept at the same potential through the operation of the amplifier. By connecting the signal conductor to the non-inverting input and letting the inverting input drive the guard, the signal conductor and the guard are kept at the same potential which prevents leakage from the signal source.

LAYOUT AND ASSEMBLY CONSIDERATIONS

In order to capitalize on the LMP7721's ultra low input bias current, careful circuit layout and assembly are required. Guarding techniques are highly recommended to reduce parasitic leakage current by isolating the LMP7721's input from large voltage gradients across the PC board. A guard is a low impedance conductor that surrounds an input line and its potential is raised to the input line's voltage. The input pins should be fully guarded as shown in Figure 6. The guard traces should completely encircle the input connections. In addition, they should be located on both sides of the PCB and be connected together.



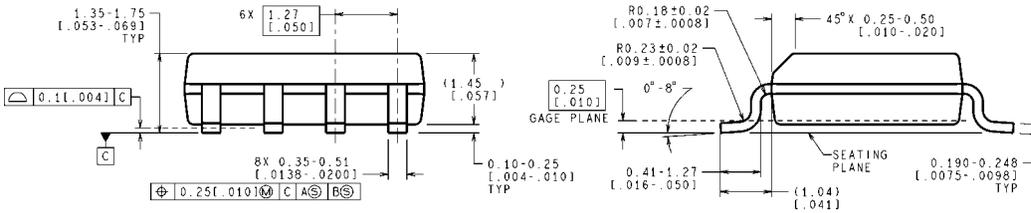
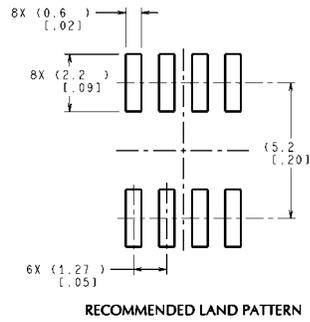
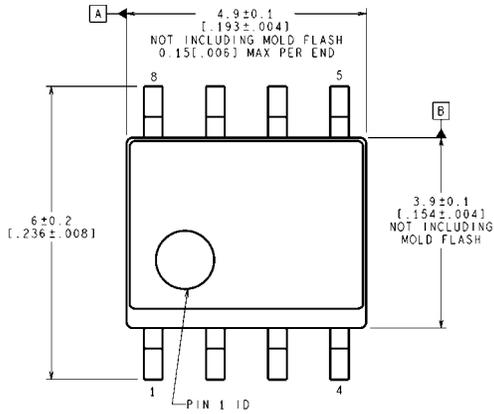
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FIGURE 6. Circuit Board Guard Layout

Solder mask should not cover the input and the guard area including guard traces on either side of the PCB.

Sockets are not recommended as they can be a significant leakage source. After assembly, a thorough cleaning using commercial solvent is necessary.

Physical Dimensions inches (millimeters) unless otherwise noted



CONTROLLING DIMENSION IS MILLIMETER
VALUES IN [] ARE INCHES
DIMENSIONS IN () FOR REFERENCE ONLY

**8-Pin SOIC
NS Package Number M08A**

M08A (Rev L)

Notes

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